

25A, 400V - 1000V Standard Bridge Rectifier

FEATURES

- Ideal for printed circuit board
- High surge current capability
- Low forward drop enhance the efficiency
- UL Recognized File # E-326243
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

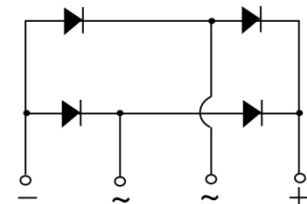
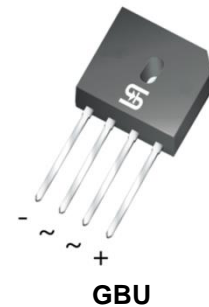
APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- Lighting application

MECHANICAL DATA

- Case: GBU
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test
- Mounting torque: 0.56 N·m maximum
- Polarity: As marked
- Weight: 4.00g (approximately)

KEY PARAMETERS		
PARAMETER	VALUE	UNIT
I_F	25	A
V_{RRM}	400 - 1000	V
I_{FSM}	300	A
$T_{J\ MAX}$	150	°C
Package	GBU	
Configuration	Quad	



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	GBU2504	GBU2505	GBU2506	GBU2507	UNIT
Marking code on the device		GBU2504	GBU2505	GBU2506	GBU2507	
Repetitive peak reverse voltage	V_{RRM}	400	600	800	1000	V
Reverse voltage, total rms value	$V_{R(RMS)}$	280	420	560	700	V
Forward current	I_F	25				A
Surge peak forward current, 8.3ms single half sine-wave superimposed on rated load	I_{FSM}	300				A
Rating for fusing ($t < 8.3\text{ms}$)	I^2t	373				A^2s
Junction temperature	T_J	- 55 to +150				°C
Storage temperature	T_{STG}	- 55 to +150				°C

THERMAL PERFORMANCE			
PARAMETER	SYMBOL	TYP	UNIT
Junction-to-lead thermal resistance	$R_{\theta JL}$	1.3	°C/W
Junction-to-ambient thermal resistance	$R_{\theta JA}$	6.7	°C/W
Junction-to-case thermal resistance	$R_{\theta JC}$	1.0	°C/W

Thermal Performance Note: Mounted on heat sink size of 4" x 6" x 0.25" Al-Plate

ELECTRICAL SPECIFICATIONS ($T_A = 25^\circ\text{C}$ unless otherwise noted)					
PARAMETER	CONDITIONS	SYMBOL	TYP	MAX	UNIT
Forward voltage per diode ⁽¹⁾	$I_F = 12.5\text{A}, T_J = 25^\circ\text{C}$	V_F	0.99	1.10	V
	$I_F = 25.0\text{A}, T_J = 25^\circ\text{C}$		1.08	1.20	V
	$I_F = 12.5\text{A}, T_J = 125^\circ\text{C}$		0.89	1.00	V
	$I_F = 25.0\text{A}, T_J = 125^\circ\text{C}$		1.03	1.15	V
Reverse current @ rated V_R per diode ⁽²⁾	$T_J = 25^\circ\text{C}$	I_R	-	10	μA
	$T_J = 125^\circ\text{C}$		-	500	μA
Junction capacitance per diode	1MHz, $V_R = 4.0\text{V}$	C_J	100	-	pF

Notes:

1. Pulse test with PW = 0.3ms
2. Pulse test with PW = 30ms

ORDERING INFORMATION		
ORDERING CODE⁽¹⁾	PACKAGE	PACKING
GBU25x	GBU	20 / Tube

Notes:

1. "x" defines voltage from 400V(GBU2504) to 1000V(GBU2507)

CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)

Fig.1 Forward Current Derating Curve

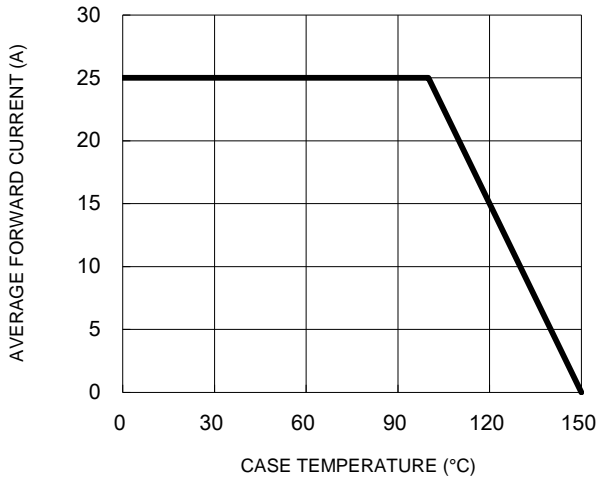


Fig.2 Typical Junction Capacitance

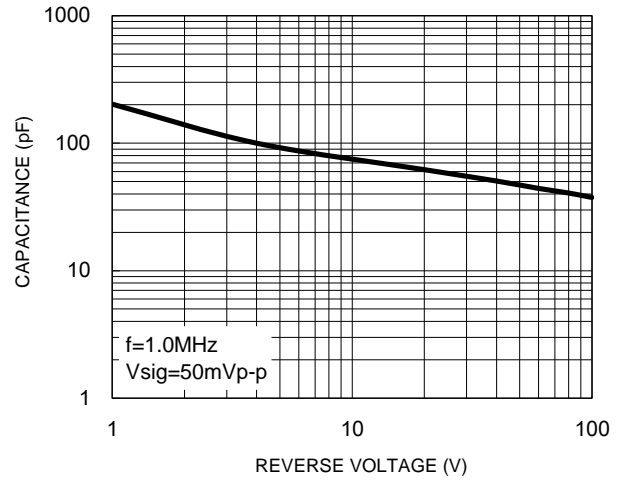


Fig.3 Typical Reverse Characteristics

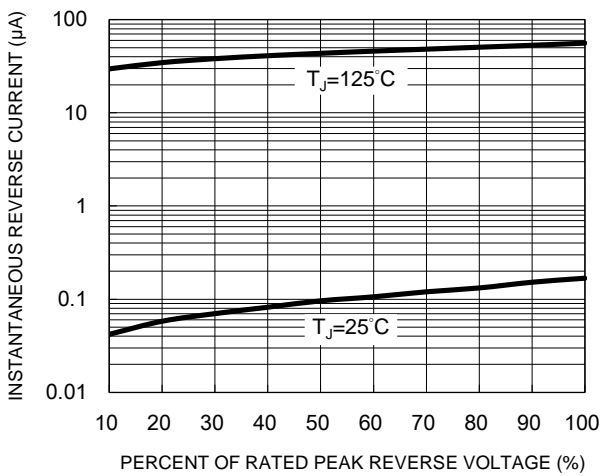
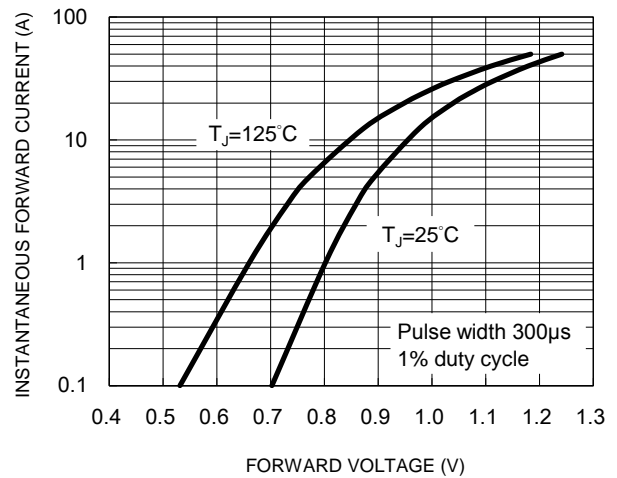
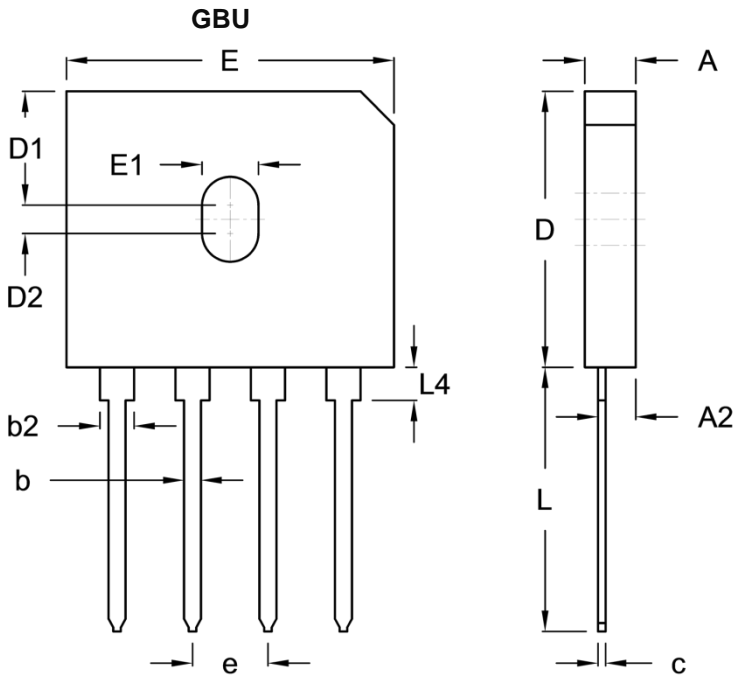


Fig.4 Typical Forward Characteristics



PACKAGE OUTLINE DIMENSIONS



DIM.	Unit (mm)		Unit (inch)	
	Min.	Max.	Min.	Max.
A	3.30	3.56	0.130	0.140
A2	2.40	2.66	0.094	0.105
b	1.02	1.27	0.040	0.050
b2	2.06	2.54	0.081	0.100
c	0.46	0.56	0.018	0.022
D	18.30	18.80	0.720	0.740
D1	7.40	7.90	0.291	0.311
D2	1.65	2.16	0.065	0.085
E	21.80	22.30	0.858	0.878
E1	3.50	4.10	0.138	0.161
e	4.83	5.33	0.190	0.210
L	17.50	18.00	0.689	0.709
L4	1.91	2.54	0.075	0.100

MARKING DIAGRAM



- P/N = Marking Code
- G = Green Compound
- YWW = Date Code
- F = Factory Code